



Welcome to E-XFL.COM

What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4/M0
Core Size	32-Bit Dual-Core
Speed	204MHz
Connectivity	CANbus, EBI/EMI, I ² C, IrDA, Microwire, SD, SPI, SSI, SSP, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I ² S, POR, WDT
Number of I/O	49
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	16K x 8
RAM Size	136K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 4x10b; D/A 1x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-TFBGA
Supplier Device Package	100-TFBGA (9x9)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/lpc4317jet100e

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P1_8	R7	H5	71	51	[2]	N; PU	I/O	GPIO1[1] — General purpose digital input/output pin.
							O	U1_DTR — Data Terminal Ready output for UART1.
							O	CTOUT_12 — SCT output 12. Match output 3 of timer 3.
							I/O	EMC_D1 — External memory data line 1.
							-	R — Function reserved.
							-	R — Function reserved.
							O	SD_VOLT0 — SD/MMC bus voltage select output 0.
P1_9	T7	J5	73	52	[2]	N; PU	I/O	GPIO1[2] — General purpose digital input/output pin.
							O	U1_RTS — Request to Send output for UART1.
							O	CTOUT_11 — SCT output 11. Match output 3 of timer 2.
							I/O	EMC_D2 — External memory data line 2.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	SD_DAT0 — SD/MMC data bus line 0.
P1_10	R8	H6	75	53	[2]	N; PU	I/O	GPIO1[3] — General purpose digital input/output pin.
							I	U1_RI — Ring Indicator input for UART1.
							O	CTOUT_14 — SCT output 14. Match output 2 of timer 3.
							I/O	EMC_D3 — External memory data line 3.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	SD_DAT1 — SD/MMC data bus line 1.
P1_11	T9	J7	77	55	[2]	N; PU	I/O	GPIO1[4] — General purpose digital input/output pin.
							I	U1_CTS — Clear to Send input for UART1.
							O	CTOUT_15 — SCT output 15. Match output 3 of timer 3.
							I/O	EMC_D4 — External memory data line 4.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	SD_DAT2 — SD/MMC data bus line 2.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P2_5	K14	D10	131	91	[3]	N; PU	I/O	SGPIO14 — General purpose digital input/output pin.
							I	CTIN_2 — SCT input 2. Capture input 2 of timer 0.
							I	USB1_VBUS — Monitors the presence of USB1 bus power. Note: This signal must be HIGH for USB reset to occur.
							I	ADCTRIG1 — ADC trigger input 1.
							I/O	GPIO5[5] — General purpose digital input/output pin.
							-	R — Function reserved.
							O	T3_MAT2 — Match output 2 of timer 3.
							O	USB0_IND0 — USB0 port indicator LED control output 0.
P2_6	K16	G9	137	95	[2]	N; PU	I/O	SGPIO7 — General purpose digital input/output pin.
							I/O	U0_DIR — RS-485/EIA-485 output enable/direction control for USART0.
							I/O	EMC_A10 — External memory address line 10.
							O	USB0_IND0 — USB0 port indicator LED control output 0.
							I/O	GPIO5[6] — General purpose digital input/output pin.
							I	CTIN_7 — SCT input 7.
							I	T3_CAP3 — Capture input 3 of timer 3.
							O	EMC_BLS1 — LOW active Byte Lane select signal 1.
P2_7	H14	C10	138	96	[2]	N; PU	I/O	GPIO0[7] — General purpose digital input/output pin. If this pin is pulled LOW at reset, the part enters ISP mode or boots from an external source (see Table 4 and Table 5).
							O	CTOUT_1 — SCT output 1. Match output 3 of timer 3.
							I/O	U3_UCLK — Serial clock input/output for USART3 in synchronous mode.
							I/O	EMC_A9 — External memory address line 9.
							-	R — Function reserved.
							-	R — Function reserved.
							O	T3_MAT3 — Match output 3 of timer 3.
							-	R — Function reserved.
P2_8	J16	C6	140	98	[2]	N; PU	I/O	SGPIO15 — General purpose digital input/output pin. Boot pin (see Table 5).
							O	CTOUT_0 — SCT output 0. Match output 0 of timer 0.
							I/O	U3_DIR — RS-485/EIA-485 output enable/direction control for USART3.
							I/O	EMC_A8 — External memory address line 8.
							I/O	GPIO5[7] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.

Table 3. Pin description ...continued

Pin name	LPGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P2_9	H16	B10	144	102	[2]	N; PU	I/O	GPIO1[10] — General purpose digital input/output pin. Boot pin (see Table 5).
							O	CTOUT_3 — SCT output 3. Match output 3 of timer 0.
							I/O	U3_BAUD — Baud pin for USART3.
							I/O	EMC_A0 — External memory address line 0.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
P2_10	G16	E8	146	104	[2]	N; PU	I/O	GPIO0[14] — General purpose digital input/output pin.
							O	CTOUT_2 — SCT output 2. Match output 2 of timer 0.
							O	U2_TXD — Transmitter output for USART2.
							I/O	EMC_A1 — External memory address line 1.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
P2_11	F16	A9	148	105	[2]	N; PU	I/O	GPIO1[11] — General purpose digital input/output pin.
							O	CTOUT_5 — SCT output 5. Match output 3 of timer 3.
							I	U2_RXD — Receiver input for USART2.
							I/O	EMC_A2 — External memory address line 2.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
P2_12	E15	B9	153	106	[2]	N; PU	I/O	GPIO1[12] — General purpose digital input/output pin.
							O	CTOUT_4 — SCT output 4. Match output 3 of timer 3.
							-	R — Function reserved.
							I/O	EMC_A3 — External memory address line 3.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	U2_UCLK — Serial clock input/output for USART2 in synchronous mode.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P6_0	M12	H7	105	73	[2]	N; PU	-	R — Function reserved.
							O	I2S0_RX_MCLK — I2S receive master clock.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	I2S0_RX_SCK — Receive Clock. It is driven by the master and received by the slave. Corresponds to the signal SCK in the <i>I²S-bus specification</i> .
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
P6_1	R15	G5	107	74	[2]	N; PU	I/O	GPIO3[0] — General purpose digital input/output pin.
							O	EMC_DYCS1 — SDRAM chip select 1.
							I/O	U0_UCLK — Serial clock input/output for USART0 in synchronous mode.
							I/O	I2S0_RX_WS — Receive Word Select. It is driven by the master and received by the slave. Corresponds to the signal WS in the <i>I²S-bus specification</i> .
							-	R — Function reserved.
							I	T2_CAP0 — Capture input 2 of timer 2.
							-	R — Function reserved.
							-	R — Function reserved.
P6_2	L13	J9	111	78	[2]	N; PU	I/O	GPIO3[1] — General purpose digital input/output pin.
							O	EMC_CKEOUT1 — SDRAM clock enable 1.
							I/O	U0_DIR — RS-485/EIA-485 output enable/direction control for USART0.
							I/O	I2S0_RX_SDA — I2S Receive data. It is driven by the transmitter and read by the receiver. Corresponds to the signal SD in the <i>I²S-bus specification</i> .
							-	R — Function reserved.
							I	T2_CAP1 — Capture input 1 of timer 2.
							-	R — Function reserved.
							-	R — Function reserved.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P8_2	K4	-	36	-	[3]	N; PU	I/O	GPIO4[2] — General purpose digital input/output pin.
							O	USB0_IND0 — USB0 port indicator LED control output 0.
							-	R — Function reserved.
							I	MCIO — Motor control PWM channel 0, input.
							I/O	SGPIO10 — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							O	T0_MAT2 — Match output 2 of timer 0.
P8_3	J3	-	37	-	[2]	N; PU	I/O	GPIO4[3] — General purpose digital input/output pin.
							I/O	USB1_ULPI_D2 — ULPI link bidirectional data line 2.
							-	R — Function reserved.
							O	LCD_VD12 — LCD data.
							O	LCD_VD19 — LCD data.
							-	R — Function reserved.
							-	R — Function reserved.
P8_4	J2	-	39	-	[2]	N; PU	O	T0_MAT3 — Match output 3 of timer 0.
							I/O	GPIO4[4] — General purpose digital input/output pin.
							I/O	USB1_ULPI_D1 — ULPI link bidirectional data line 1.
							-	R — Function reserved.
							O	LCD_VD7 — LCD data.
							O	LCD_VD16 — LCD data.
							-	R — Function reserved.
P8_5	J1	-	40	-	[2]	N; PU	-	R — Function reserved.
							I	T0_CAP0 — Capture input 0 of timer 0.
							I/O	GPIO4[5] — General purpose digital input/output pin.
							I/O	USB1_ULPI_D0 — ULPI link bidirectional data line 0.
							-	R — Function reserved.
							O	LCD_VD6 — LCD data.
							O	LCD_VD8 — LCD data.
							-	R — Function reserved.
							-	R — Function reserved.
							I	T0_CAP1 — Capture input 1 of timer 0.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P8_6	K3	-	43	-	[2]	N; PU	I/O	GPIO4[6] — General purpose digital input/output pin.
							I	USB1_ULPI_NXT — ULPI link NXT signal. Data flow control signal from the PHY.
							-	R — Function reserved.
							O	LCD_VD5 — LCD data.
							O	LCD_LP — Line synchronization pulse (STN). Horizontal synchronization pulse (TFT).
							-	R — Function reserved.
							-	R — Function reserved.
							I	T0_CAP2 — Capture input 2 of timer 0.
P8_7	K1	-	45	-	[2]	N; PU	I/O	GPIO4[7] — General purpose digital input/output pin.
							O	USB1_ULPI_STP — ULPI link STP signal. Asserted to end or interrupt transfers to the PHY.
							-	R — Function reserved.
							O	LCD_VD4 — LCD data.
							O	LCD_PWR — LCD panel power enable.
							-	R — Function reserved.
							-	R — Function reserved.
P8_8	L1	-	49	-	[2]	N; PU	-	R — Function reserved.
							I	USB1_ULPI_CLK — ULPI link CLK signal. 60 MHz clock generated by the PHY.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							O	CGU_OUT0 — CGU spare clock output 0.
							O	I2S1_TX_MCLK — I2S1 transmit master clock.
P9_0	T1	-	59	-	[2]	N; PU	I/O	GPIO4[12] — General purpose digital input/output pin.
							O	MCABORT — Motor control PWM, LOW-active fast abort.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							I	ENET_CRS — Ethernet Carrier Sense (MII interface).
							I/O	SGPIO0 — General purpose digital input/output pin.
							I/O	SSP0_SSEL — Slave Select for SSP0.

Table 3. Pin description ...continued

Pin name	LPGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
PE_2	M14	-	115	-	[2]	N; PU	I	ADCTRIG0 — ADC trigger input 0.
							I	CAN0_RD — CAN receiver input.
							-	R — Function reserved.
							I/O	EMC_A20 — External memory address line 20.
							I/O	GPIO7[2] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
PE_3	K12	-	118	-	[2]	N; PU	-	R — Function reserved.
							O	CAN0_TD — CAN transmitter output.
							I	ADCTRIG1 — ADC trigger input 1.
							I/O	EMC_A21 — External memory address line 21.
							I/O	GPIO7[3] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
PE_4	K13	-	120	-	[2]	N; PU	-	R — Function reserved.
							I	NMI — External interrupt input to NMI.
							-	R — Function reserved.
							I/O	EMC_A22 — External memory address line 22.
							I/O	GPIO7[4] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
PE_5	N16	-	122	-	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_3 — SCT output 3. Match output 3 of timer 0.
							O	U1_RTS — Request to Send output for UART 1. Can also be configured to be an RS-485/EIA-485 output enable signal for UART 1.
							I/O	EMC_D24 — External memory data line 24.
							I/O	GPIO7[5] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.

The LCD controller provides all of the necessary control signals to interface directly to various color and monochrome LCD panels. Both STN (single and dual panel) and TFT panels can be operated. The display resolution is selectable and can be up to 1024×768 pixels. Several color modes are provided, up to a 24-bit true-color non-palettized mode. An on-chip 512 byte color palette allows reducing bus utilization (that is, memory size of the displayed data) while still supporting many colors.

The LCD interface includes its own DMA controller to allow it to operate independently of the CPU and other system functions. A built-in FIFO acts as a buffer for display data, providing flexibility for system timing. Hardware cursor support can further reduce the amount of CPU time required to operate the display.

7.18.7.1 Features

- AHB master interface to access frame buffer.
- Setup and control via a separate AHB slave interface.
- Dual 16-deep programmable 64-bit wide FIFOs for buffering incoming display data.
- Supports single and dual-panel monochrome Super Twisted Nematic (STN) displays with 4-bit or 8-bit interfaces.
- Supports single and dual-panel color STN displays.
- Supports Thin Film Transistor (TFT) color displays.
- Programmable display resolution including, but not limited to: 320×200 , 320×240 , 640×200 , 640×240 , 640×480 , 800×600 , and 1024×768 .
- Hardware cursor support for single-panel displays.
- 15 gray-level monochrome, 3375 color STN, and 32 K color palettized TFT support.
- 1, 2, or 4 bits-per-pixel (bpp) palettized displays for monochrome STN.
- 1, 2, 4, or 8 bpp palettized color displays for color STN and TFT.
- 16 bpp true-color non-palettized for color STN and TFT.
- 24 bpp true-color non-palettized for color TFT.
- Programmable timing for different display panels.
- 256 entry, 16-bit palette RAM, arranged as a 128×32 -bit RAM.
- Frame, line, and pixel clock signals.
- AC bias signal for STN, data enable signal for TFT panels.
- Supports little and big-endian, and Windows CE data formats.
- LCD panel clock may be generated from the peripheral clock, or from a clock input pin.

7.18.8 Ethernet

Remark: The ethernet controller is available on parts LPC435x and LPC433x. Ethernet is not available on parts LPC432x and LPC431x.

7.18.8.1 Features

- 10/100 Mbit/s
- DMA support
- Power management remote wake-up frame and magic packet detection

There are three levels of the Code Read Protection:

- In level CRP1, access to the chip via the JTAG is disabled. Partial flash updates are allowed (excluding flash sector 0) using a limited set of the ISP commands. This level is useful when CRP is required and flash field updates are needed. CRP1 does prevent the user code from erasing all sectors.
- In level CRP2, access to the chip via the JTAG is disabled. Only a full flash erase and update using a reduced set of the ISP commands is allowed.
- In level CRP3, any access to the chip via the JTAG pins or the ISP is disabled. This mode also disables the ISP override using P2_7 pin. If necessary, the application code must provide a flash update mechanism using the IAP calls or using the reinvoke ISP command to enable flash update via USART0. See [Table 5](#).

CAUTION



If level three Code Read Protection (CRP3) is selected, no future factory testing can be performed on the device.

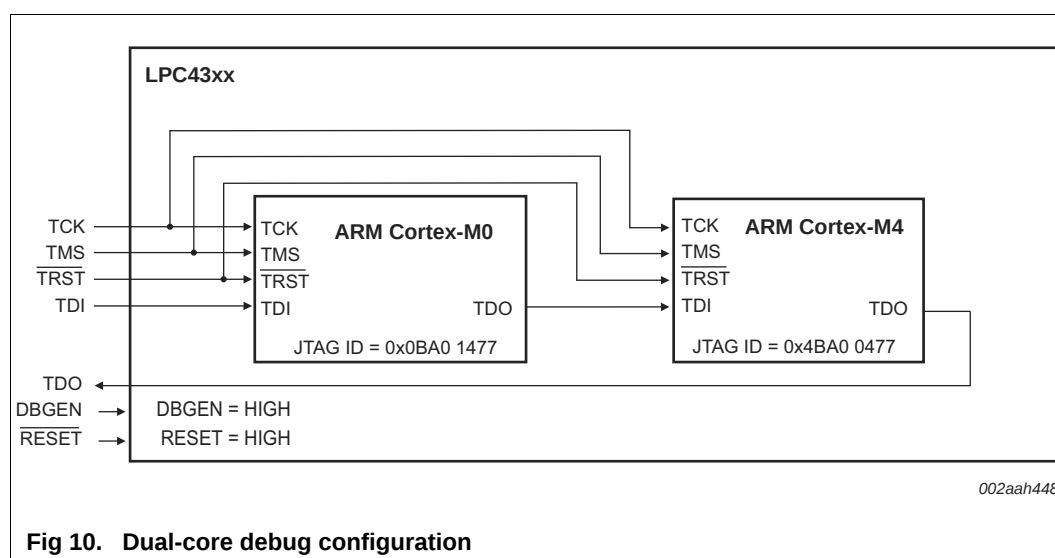
7.24 Serial Wire Debug/JTAG

Debug and trace functions are integrated into the ARM Cortex-M4. Serial wire debug and trace functions are supported in addition to a standard JTAG debug and parallel trace functions. The ARM Cortex-M4 is configured to support up to eight breakpoints and four watch points.

Remark: Serial Wire Debug is supported for the ARM Cortex-M4 only,

The ARM Cortex-M0 coprocessor supports JTAG debug. A standard ARM Cortex-compliant debugger can debug the ARM Cortex-M4 and the ARM Cortex-M0 cores separately or both cores simultaneously.

Remark: In order to debug the ARM Cortex-M0, release the M0 reset by software in the RGU block.



8. Limiting values

Table 7. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).^[1]

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DD(REG)(3V3)}	regulator supply voltage (3.3 V)	on pin VDDREG		−0.5	3.6	V
V _{DD(IO)}	input/output supply voltage	on pin VDDIO		−0.5	3.6	V
V _{DDA(3V3)}	analog supply voltage (3.3 V)	on pin VDDA		−0.5	3.6	V
V _{BAT}	battery supply voltage	on pin VBAT		−0.5	3.6	V
V _{prog(pf)}	polyfuse programming voltage	on pin VPP		−0.5	3.6	V
V _I	input voltage	when V _{DD(IO)} ≥ 2.4 V	[2]	−0.5	5.5	V
		5 V tolerant digital I/O pins				
		ADC/DAC pins and digital I/O pins configured for an analog function		−0.5	V _{DDA(3V3)}	V
		USB0 pins USB0_DP; USB0_DM; USB0_VBUS		−0.3	5.25	V
		USB0 pins USB0_ID; USB0_RREF		−0.3	3.6	V
		USB1 pins USB1_DP and USB1_DM		−0.3	5.25	V
I _{DD}	supply current	per supply pin		-	100	mA
I _{SS}	ground current	per ground pin		-	100	mA
I _{latch}	I/O latch-up current	−(0.5V _{DD(IO)}) < V _I < (1.5V _{DD(IO)}); T _j < 125 °C		-	100	mA
T _{stg}	storage temperature		[3]	−65	+150	°C
P _{tot(pack)}	total power dissipation (per package)	based on package heat transfer, not device power consumption		-	1.5	W
V _{ESD}	electrostatic discharge voltage	human body model; all pins	[4]	-	2000	V

[1] The following applies to the limiting values:

- Absolute maximum ratings state the extreme limits that the product can withstand without leading to irrecoverable failure. Failure includes the loss of reliability and shorter lifetime of the device. Conditions for functional operation of the part are shown in [Table 11](#) "Static characteristics".
- This product includes circuitry designed for the protection of its internal devices from the damaging effects of excessive static charge. Nonetheless, it is suggested that conventional precautions be taken to avoid applying greater than the rated maximum.
- Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V_{SS} unless otherwise noted.

[2] Including voltage on outputs in 3-state mode.

[3] Dependent on package type.

[4] Human body model: equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.

9. Thermal characteristics

The average chip junction temperature, T_j (°C), can be calculated using the following equation:

$$T_j = T_{amb} + (P_D \times R_{th(j-a)}) \quad (1)$$

- T_{amb} = ambient temperature (°C),
- $R_{th(j-a)}$ = the package junction-to-ambient thermal resistance (°C/W)
- P_D = sum of internal and I/O power dissipation

The internal power dissipation is the product of I_{DD} and V_{DD} . The I/O power dissipation of the I/O pins is often small and many times can be negligible. However it can be significant in some applications.

Table 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{j(max)}$	maximum junction temperature	-	-	-	125	°C

Table 9. Thermal resistance (LQFP packages)

Symbol	Parameter	Conditions	Thermal resistance in °C/W ±15 %	
			LQFP144	LQFP208
$R_{th(j-a)}$	thermal resistance from junction to ambient	JEDEC (4.5 in × 4 in); still air	38	31
		Single-layer (4.5 in × 3 in); still air	50	39
$R_{th(j-c)}$	thermal resistance from junction to case	-	11	10

Table 10. Thermal resistance value (BGA packages)

Symbol	Parameter	Conditions	Thermal resistance in °C/W ±15 %	
			LBGA256	TFBGA100
$R_{th(j-a)}$	thermal resistance from junction to ambient	JEDEC (4.5 in × 4 in); still air	29	46
		8-layer (4.5 in × 3 in); still air	24	37
$R_{th(j-c)}$	thermal resistance from junction to case		14	11

10. Static characteristics

Table 11. Static characteristics

$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+105\text{ }^{\circ}\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ ^[1]	Max	Unit
Supply pins							
$V_{DD(I/O)}$	input/output supply voltage		[17]	2.4	-	3.6	V
$V_{DD(REG)(3V3)}$	regulator supply voltage (3.3 V)		[2]	2.4	-	3.6	V
$V_{DDA(3V3)}$	analog supply voltage (3.3 V)	on pin VDDA		2.4	-	3.6	V
		on pins USB0_VDDA3V3_DRIVER and USB0_VDDA3V3		3.0	3.3	3.6	V
V_{BAT}	battery supply voltage		[2]	2.4	-	3.6	V
$V_{prog(pf)}$	polyfuse programming voltage	on pin VPP (for OTP)	[3]	2.7	-	3.6	V
$I_{prog(pf)}$	polyfuse programming current	on pin VPP; OTP programming time $\leq 1.6\text{ ms}$		-	-	30	mA
$I_{DD(REG)(3V3)}$	regulator supply current (3.3 V)	Active mode; ARM Cortex-M0 core in reset; code <code>while(1){}</code> executed from RAM; all peripherals disabled; PLL1 enabled					
		CCLK = 12 MHz	[4]	-	10	-	mA
		CCLK = 60 MHz	[4]		28	-	mA
		CCLK = 120 MHz	[4]	-	51	-	mA
		CCLK = 180 MHz	[4]	-	74	-	mA
		CCLK = 204 MHz	[4]	-	83	-	mA
$I_{DD(REG)(3V3)}$	regulator supply current (3.3 V)	after WFE/WFI instruction executed from RAM; all peripherals disabled; ARM Cortex-M0 core in reset					
		sleep mode	[4][5]	-	8.8	-	mA
		deep-sleep mode	[4]	-	145	-	μA
		power-down mode	[4]	-	23	-	μA
		deep power-down mode	[4][6]	-	0.05	-	μA
		deep power-down mode; VBAT floating	[4]	-	3.0	-	μA
I_{BAT}	battery supply current	$V_{BAT} = 3.0\text{ V}$; $V_{DD(REG)(3V3)} = 3.3\text{ V}$	[7]	-		0.1	nA

Table 11. Static characteristics ...continued $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+105\text{ }^{\circ}\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ ^[1]	Max	Unit
V_{IC}	common-mode input voltage	high-speed mode		-50	200	500	mV
		full-speed/low-speed mode		800	-	2500	mV
		chirp mode		-50	-	600	mV
$V_{i(dif)}$	differential input voltage			100	400	1100	mV
USB1 pins (USB1_DP/USB1_DM)^[17]							
I_{OZ}	OFF-state output current	$0\text{ V} < V_I < 3.3\text{ V}$	^[17]	-	-	± 10	μA
V_{BUS}	bus supply voltage		^[18]	-	-	5.25	V
V_{DI}	differential input sensitivity voltage	$ (D+) - (D-) $		0.2	-	-	V
V_{CM}	differential common mode voltage range	includes V_{DI} range		0.8	-	2.5	V
$V_{th(rs)se}$	single-ended receiver switching threshold voltage			0.8	-	2.0	V
V_{OL}	LOW-level output voltage for low-/full-speed	R_L of 1.5 k Ω to 3.6 V		-	-	0.18	V
V_{OH}	HIGH-level output voltage (driven) for low-/full-speed	R_L of 15 k Ω to GND		2.8	-	3.5	V
C_{trans}	transceiver capacitance	pin to GND		-	-	20	pF
Z_{DRV}	driver output impedance for driver which is not high-speed capable	with 33 Ω series resistor; steady state drive	^[19]	36	-	44.1	Ω

[1] Typical ratings are not guaranteed. The values listed are at room temperature (25 $^{\circ}\text{C}$), nominal supply voltages.

[2] The recommended operating condition for the battery supply is $V_{DD(Reg)(3V3)} > V_{BAT} + 0.2\text{ V}$. Special conditions for $V_{DD(Reg)(3V3)}$ apply when writing to the flash and EEPROM. See [Table 14](#) and [Table 15](#).

[3] Pin VPP should either be not connected (when OTP does not need to be programmed) or tied to pins VDDIO and VDDREG to ensure the same ramp-up time for both supply voltages.

[4] $V_{DD(Reg)(3V3)} = 3.3\text{ V}$; $V_{DD(IO)} = 3.3\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

[5] PLL1 disabled; IRC running; CCLK = 12 MHz.

[6] $V_{BAT} = 3.6\text{ V}$.

[7] $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+105\text{ }^{\circ}\text{C}$; $V_{DD(IO)} = V_{DDA} = 3.6\text{ V}$; over entire frequency range CCLK = 12 MHz to 204 MHz; in active mode, sleep mode; deep-sleep mode, power-down mode, and deep power-down mode.

[8] On pin VBAT; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

[9] V_{ps} corresponds to the output of the power switch (see [Table 9](#)) which is determined by the greater of V_{BAT} and $V_{DD(Reg)(3V3)}$.

[10] $V_{DDA(3V3)} = 3.3\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

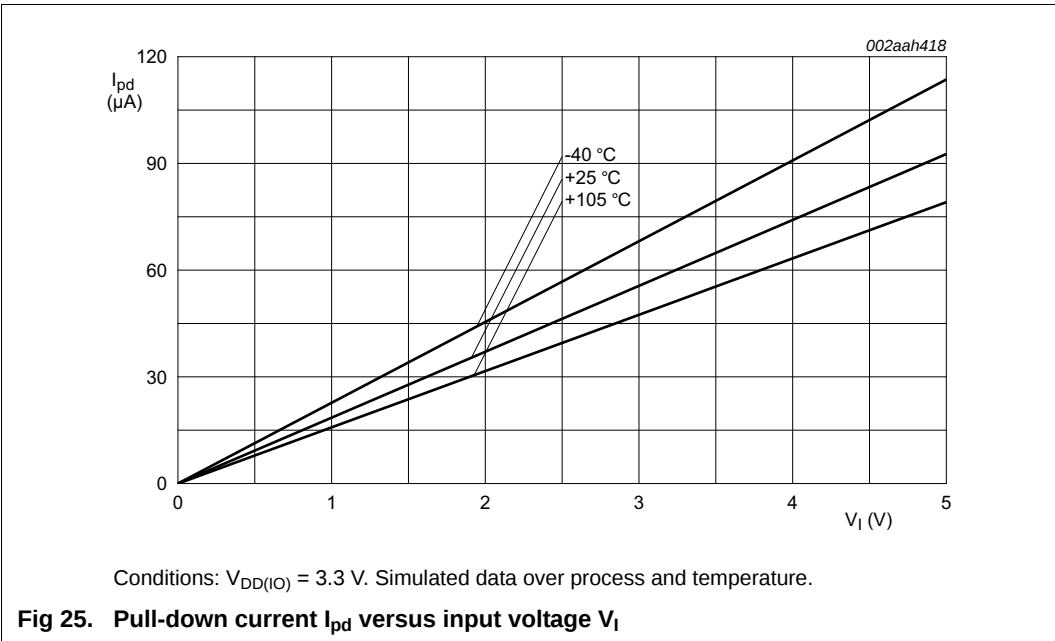
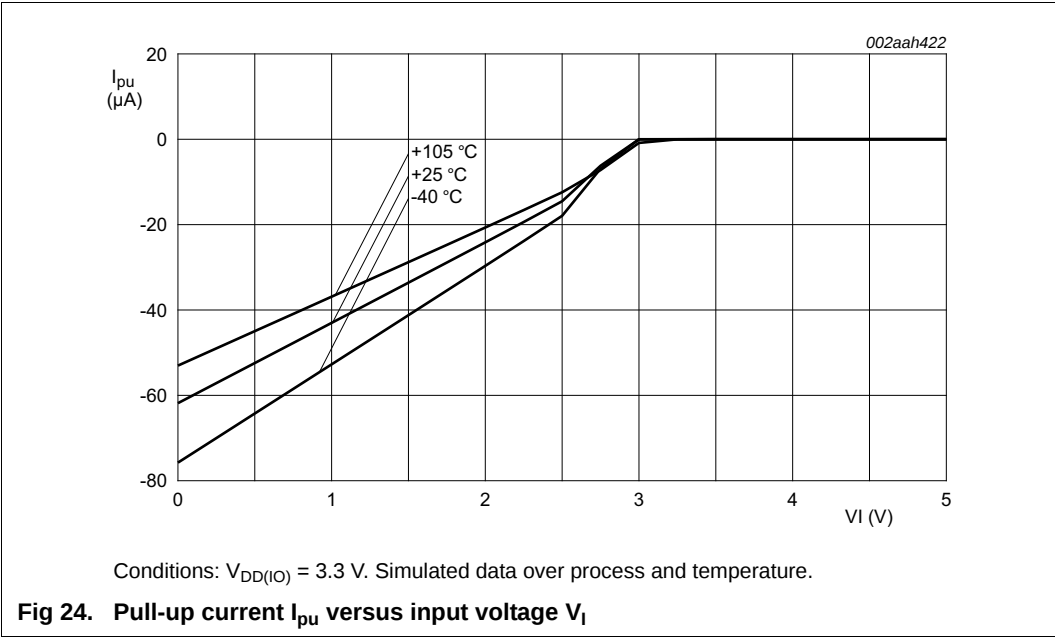
[11] Allowed as long as the current limit does not exceed the maximum current allowed by the device.

[12] To V_{SS} .

[13] The values specified are simulated and absolute values.

[14] The weak pull-up resistor is connected to the $V_{DD(IO)}$ rail and pulls up the I/O pin to the $V_{DD(IO)}$ level.

[15] The input cell disables the weak pull-up resistor when the applied input voltage exceeds $V_{DD(IO)}$.



- [9] A Fast-mode I²C-bus device can be used in a Standard-mode I²C-bus system but the requirement $t_{\text{SU;DAT}} = 250 \text{ ns}$ must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line $t_{\text{r(max)}} + t_{\text{SU;DAT}} = 1000 + 250 = 1250 \text{ ns}$ (according to the Standard-mode I²C-bus specification) before the SCL line is released. Also the acknowledge timing must meet this set-up time.

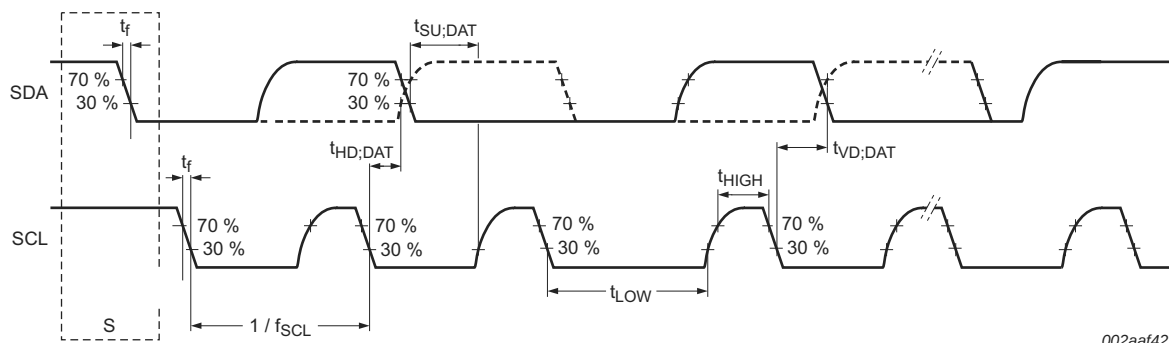


Fig 27. I²C-bus pins clock timing

11.10 I²S-bus interface

Table 25. Dynamic characteristics: I²S-bus interface pins

$T_{\text{amb}} = -40 \text{ }^{\circ}\text{C}$ to $105 \text{ }^{\circ}\text{C}$; $2.4 \text{ V} \leq V_{\text{DD(REG)(3V3)}} \leq 3.6 \text{ V}$; $2.7 \text{ V} \leq V_{\text{DD(IO)}} \leq 3.6 \text{ V}$; $C_L = 20 \text{ pF}$. Conditions and data refer to I2S0 and I2S1 pins. Simulated values.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
common to input and output							
t _r	rise time			-	4	-	ns
t _f	fall time			-	4	-	ns
t _{WH}	pulse width HIGH	on pins I2Sx_TX_SCK and I2Sx_RX_SCK		36	-	-	ns
t _{WL}	pulse width LOW	on pins I2Sx_TX_SCK and I2Sx_RX_SCK		36	-	-	ns
output							
t _{v(Q)}	data output valid time	on pin I2Sx_TX_SDA	[1]	-	4.4	-	ns
		on pin I2Sx_TX_WS		-	4.3	-	ns
input							
t _{su(D)}	data input set-up time	on pin I2Sx_RX_SDA	[1]	-	0	-	ns
		on pin I2Sx_RX_WS			0.20		ns
t _{h(D)}	data input hold time	on pin I2Sx_RX_SDA	[1]	-	3.7	-	ns
		on pin I2Sx_RX_WS		-	3.9	-	ns

[1] Clock to the I²S-bus interface $\text{BASE_APB1_CLK} = 150 \text{ MHz}$; peripheral clock to the I²S-bus interface $\text{PCLK} = \text{BASE_APB1_CLK} / 12$. I²S clock cycle time $T_{\text{cy(clk)}} = 79.2 \text{ ns}$, corresponds to the SCK signal in the I²S-bus specification.

11.18 USB interface

Table 34. Dynamic characteristics: USB0 and USB1 pins (full-speed)

$C_L = 50 \text{ pF}$; $R_{pu} = 1.5 \text{ k}\Omega$ on D+ to $V_{DD(I/O)}$, unless otherwise specified; $3.0 \text{ V} \leq V_{DD(I/O)} \leq 3.6 \text{ V}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_r	rise time	10 % to 90 %	4.0	-	20.0	ns
t_f	fall time	10 % to 90 %	4.0	-	20.0	ns
t_{FRFM}	differential rise and fall time matching	t_r / t_f	90	-	111.11	%
V_{CRS}	output signal crossover voltage		1.3	-	2.0	V
t_{FEOPT}	source SE0 interval of EOP	see Figure 38	160	-	175	ns
t_{FDEOP}	source jitter for differential transition to SE0 transition	see Figure 38	-2	-	+5	ns
t_{JR1}	receiver jitter to next transition		-18.5	-	+18.5	ns
t_{JR2}	receiver jitter for paired transitions	10 % to 90 %	-9	-	+9	ns
t_{EOPR1}	EOP width at receiver	must reject as EOP; see Figure 38	[1]	40	-	ns
t_{EOPR2}	EOP width at receiver	must accept as EOP; see Figure 38	[1]	82	-	ns

[1] Characterized but not implemented as production test. Guaranteed by design.

Remark: If only USB0 (HS USB) is used, the pins VDDREG and VDDIO can be at different voltages within the operating range but should have the same ramp up time. If USB1(FS USB) is used, the pins VDDREG and VDDIO should be a minimum of 3.0 V and be tied together.

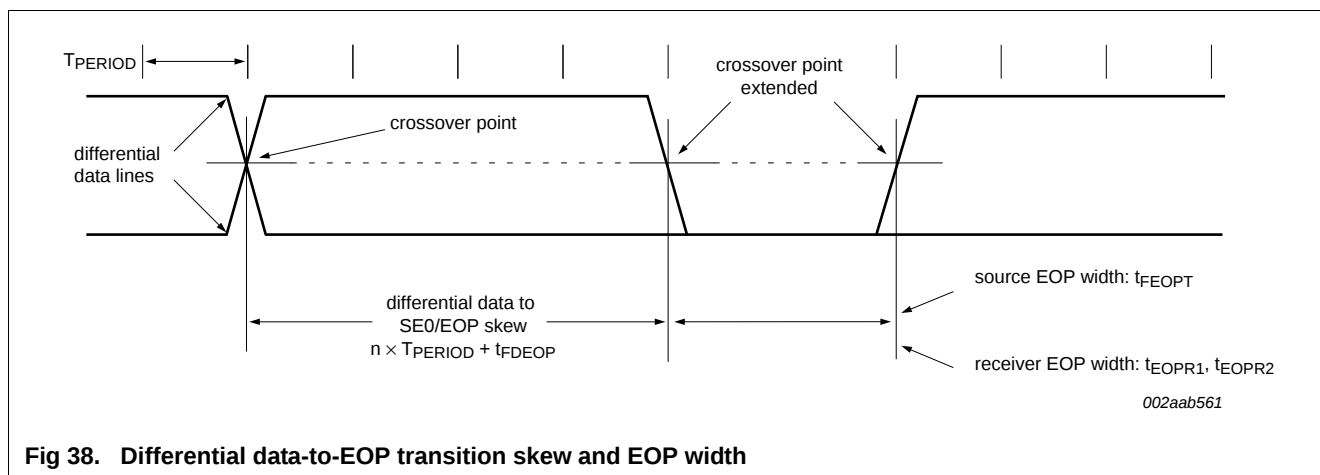


Fig 38. Differential data-to-EOP transition skew and EOP width

Table 44. Recommended values for C_{X1/X2} in oscillation mode (crystal and external components parameters) low frequency mode

Fundamental oscillation frequency	Maximum crystal series resistance R _S	External load capacitors C _{X1} , C _{X2}
12 MHz	< 160 Ω	18 pF, 18 pF
	< 160 Ω	39 pF, 39 pF
16 MHz	< 120 Ω	18 pF, 18 pF
	< 80 Ω	33 pF, 33 pF
20 MHz	< 100 Ω	18 pF, 18 pF
	< 80 Ω	33 pF, 33 pF

Table 45. Recommended values for C_{X1/X2} in oscillation mode (crystal and external components parameters) high frequency mode

Fundamental oscillation frequency	Maximum crystal series resistance R _S	External load capacitors C _{X1} , C _{X2}
15 MHz	< 80 Ω	18 pF, 18 pF
20 MHz	< 80 Ω	39 pF, 39 pF
	< 100 Ω	47 pF, 47 pF

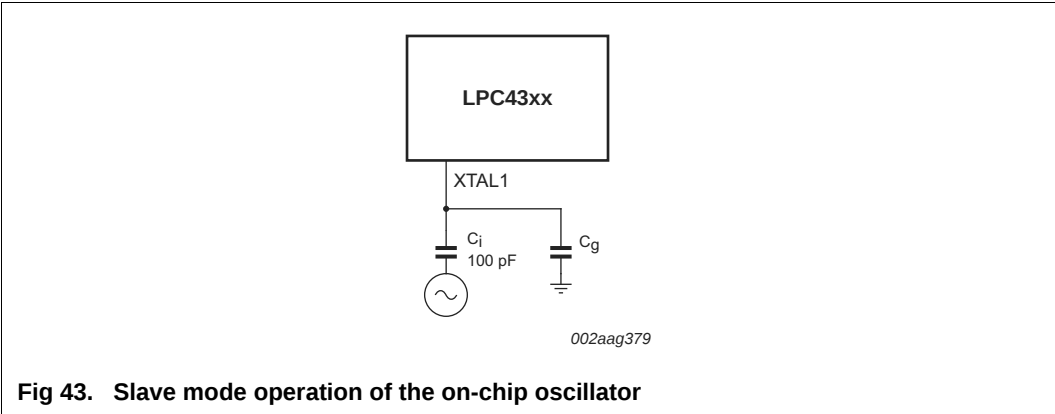


Fig 43. Slave mode operation of the on-chip oscillator

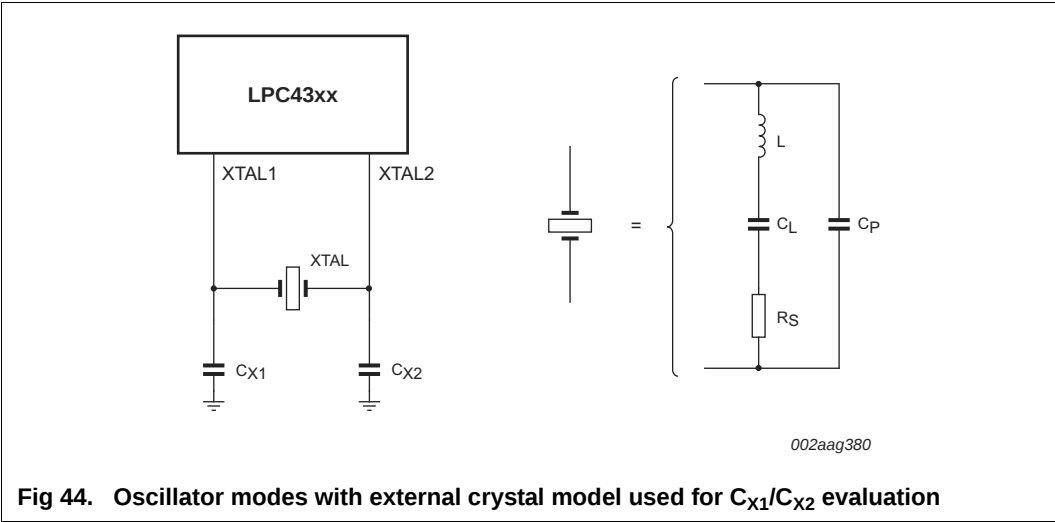


Fig 44. Oscillator modes with external crystal model used for C_{X1}/C_{X2} evaluation

14. Package outline

LPGA256: plastic low profile ball grid array package; 256 balls; body 17 x 17 x 1 mmSOT740-2

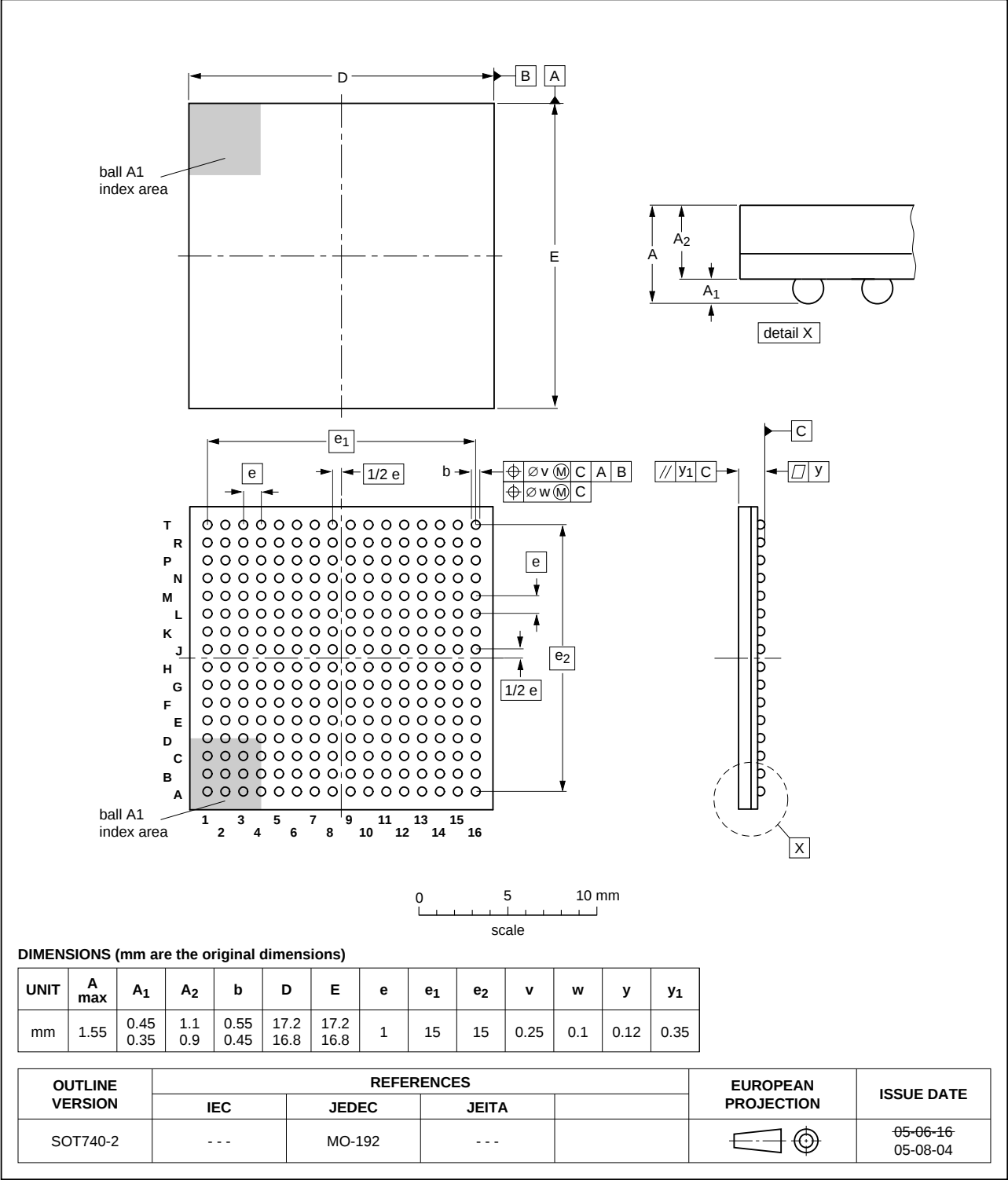


Fig 51. Package outline LPGA256 package

LQFP144: plastic low profile quad flat package; 144 leads; body 20 x 20 x 1.4 mm

SOT486-1

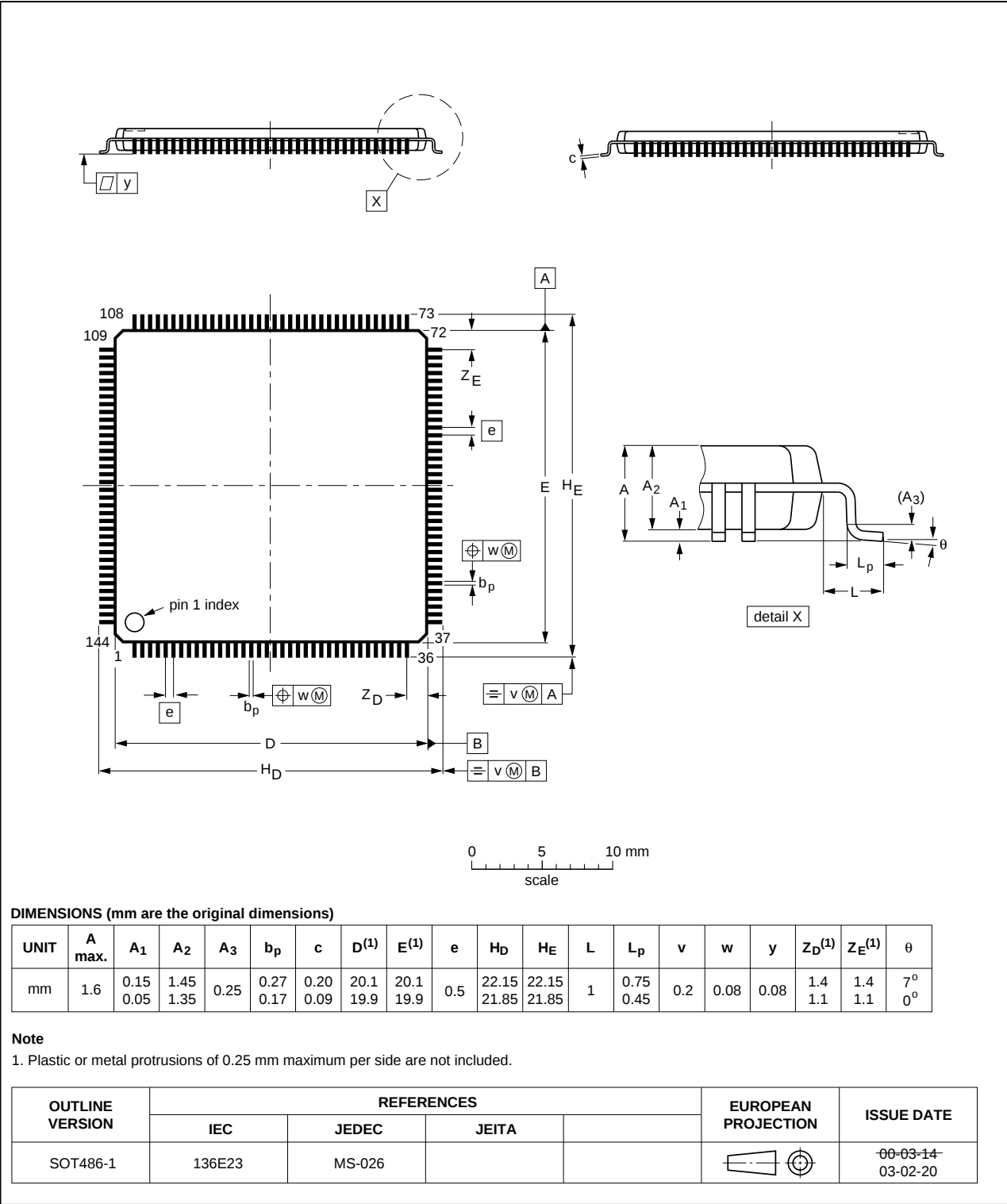
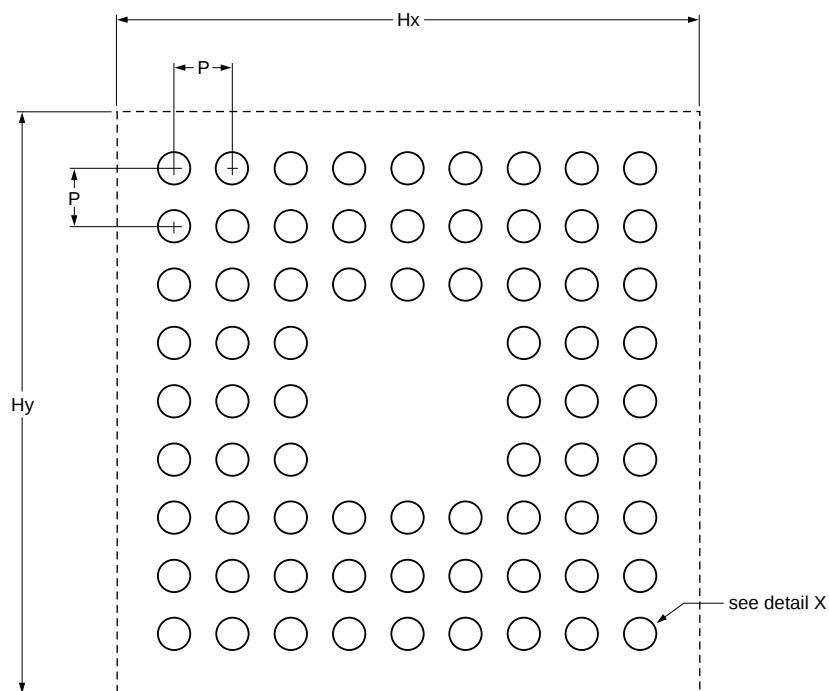


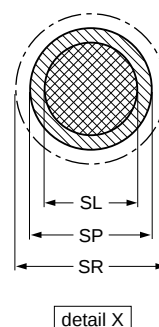
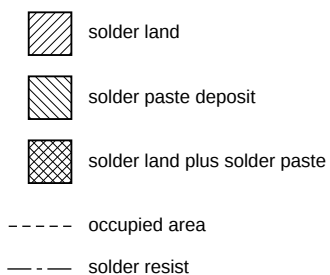
Fig 54. Package outline for the LQFP144 package

Footprint information for reflow soldering of TFBGA100 package

SOT926-1



Generic footprint pattern
Refer to the package outline drawing for actual layout



DIMENSIONS in mm

P	SL	SP	SR	Hx	Hy
0.80	0.330	0.400	0.480	9.400	9.400

sot926-1 fr

Fig 58. Reflow soldering of the TFBGA100 package